# Alpha \& Omega Semiconductor Product Reliability qualification Report 

AONS66814, rev A

Plastic Encapsulated Device

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This AOS product reliability report summarizes the qualification result for AONS66814.
Accelerated environmental tests are performed on a specific sample size, and then followed by electrical test at end point. Review of final electrical test result confirms that AONS66814 passes AOS quality and reliability requirements. The released product will be categorized by the process family and be routine monitored for continuously improving the product quality.
I. Reliability Stress Test Summary and Results

| Test Item | Test Condition | Time Point | Total Sample Size | Number of Failures | Reference Standard |
| :---: | :---: | :---: | :---: | :---: | :---: |
| HTGB | $\begin{gathered} \text { Temp }=175^{\circ} \mathrm{C}, \\ \text { Vgs }=100 \% \text { of } \mathrm{Vgsmax} \end{gathered}$ | 1000 hrs | 231 pcs | 0 | JESD22-A108 |
| HTRB | $\begin{gathered} \text { Temp }=175^{\circ} \mathrm{C}, \\ \text { Vds }=100 \% \text { of Vdsmax } \end{gathered}$ | 1000 hrs | 231 pcs | 0 | JESD22-A108 |
| HAST | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@ $260^{\circ} \mathrm{C}$ (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | $\begin{gathered} 130^{\circ} \mathrm{C}, 85 \% \mathrm{RH}, \\ 33.3 \text { psia, } \\ \text { Vds }=80 \% \text { of Vdsmax } \\ \text { up to } 42 \mathrm{~V} \\ \hline \end{gathered}$ | 96 hrs |  | 0 | JESD22-A110 |
| H3TRB | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@260ㅇ (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | $85^{\circ} \mathrm{C}, 85 \% \mathrm{RH}$, <br> Vds = 80\% of Vdsmax | 1000 hrs |  | 0 | JESD22-A101 |
| Autoclave | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@260응 (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | $\begin{gathered} 121^{\circ} \mathrm{C}, 29.7 \mathrm{psia}, \\ \text { RH }=100 \% \end{gathered}$ | 96 hrs |  | 0 | JESD22-A102 |
| Temperature Cycle | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@260ㅇ (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$, air to air | 1000 cycles |  | 0 | JESD22-A104 |
| HTSL | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@260ㅇ (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | Temp $=175^{\circ} \mathrm{C}$ | 1000 hrs |  | 0 | JESD22-A103 |
| IOL | $168 \mathrm{hr} 85^{\circ} \mathrm{C} / 85 \% \mathrm{RH}+$ 3 cycle reflow@260응 (MSL 1)* | - | 231 pcs | 0 | JESD22-A113 |
|  | $\Delta \mathrm{Tj}=100^{\circ} \mathrm{C}$ | 15000 cycles |  | 0 | MIL-STD-750 <br> Method 1037 |

Note: The reliability data presents total of available generic data up to the published date.
*: MSL (Moisture Sensitivity Level) 1 based on J-STD-020

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## II. Reliability Evaluation

## FIT rate (per billion): 2.61 <br> MTTF = 43670 years

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

Failure Rate $=\mathrm{Chi}^{2} \times 10^{9} /[2(\mathrm{~N})(\mathrm{H})(\mathrm{Af})]=2.61$
MTTF $=10^{9} /$ FIT $=43670$ years
Chi ${ }^{2}=$ Chi Squared Distribution, determined by the number of failures and confidence interval
$\mathbf{N}=$ Total Number of units from burn-in tests
$\mathbf{H}=$ Duration of burn-in testing
$\mathbf{A f}=$ Acceleration Factor from Test to Use Conditions (Ea $=0.7 \mathrm{eV}$ and Tuse $=55^{\circ} \mathrm{C}$ )
Acceleration Factor [Af] $=\operatorname{Exp}[E a / k(1 / T j u-1 / T j s)]$
Acceleration Factor ratio list:

|  | $55 \operatorname{deg} C$ | $70 \operatorname{deg} C$ | $85 \operatorname{deg} C$ | $100 \operatorname{deg} C$ | $125 \operatorname{deg} C$ | $150 \operatorname{deg} \mathbf{C}$ | $175 \operatorname{deg} \mathbf{C}$ |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Af | 758 | 256 | 95 | 38 | 9.7 | 2.9 | 1 |

Tj s = Stressed junction temperature in degree (Kelvin), $\mathrm{K}=\mathrm{C}+273.16$
Tj $\mathbf{u}=$ The use junction temperature in degree (Kelvin), $\mathrm{K}=\mathrm{C}+273.16$
$\mathbf{k}=$ Boltzmann's constant, $8.617164 \times 10^{-5} \mathrm{eV} / \mathrm{K}$

